TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC245P,TC74AC245F,TC74AC245FW,TC74AC245FT TC74AC640P,TC74AC640F,TC74AC640FW,TC74AC640FT

Octal Bus Transceiver

TC74AC245P/F/FW/FT 3-State, Non-Inverting TC74AC640P/F/FW/FT 3-State, Inverting

The TC74AC245, 640 are advanced high speed CMOS OCTAL BUS TRANSCEIVERs fabricated with silicon gate and double-layer metal wiring  $C^2MOS$  technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

They are intended for two-way asynchronous communication between data busses. The direction of data transmission is determined by the level of the DIR input.

The enable input (  $\overline{\rm G}$  ) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### Features (Note 1)(Note 2)

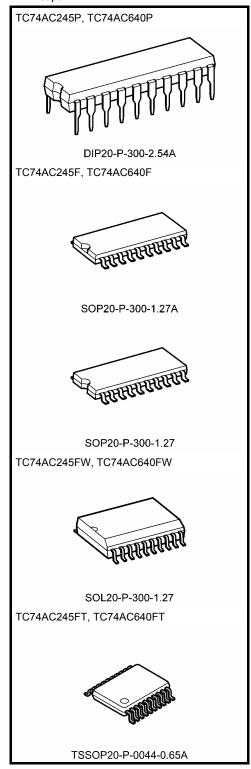
- High speed: t<sub>pd</sub> = 3.9 ns (typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation:  $I_{CC} = 8 \mu A \text{ (max)}$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance:
   |I<sub>OH</sub>| = I<sub>OL</sub> = 24 mA (min)

Capability of driving 50  $\Omega$  transmission lines.

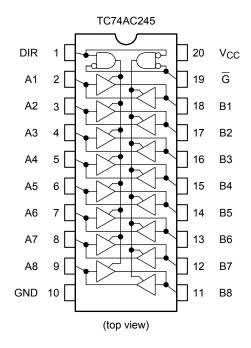
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2 V to 5.5 V
- Pin and function compatible with 74F245/640
  - Note 1: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.
  - Note 2: All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.

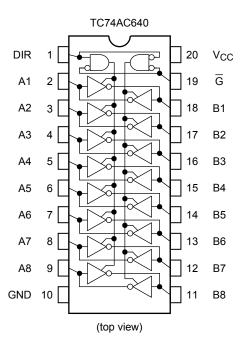
Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) Note: xxxFW (JEDEC SOP) is not available in Japan.

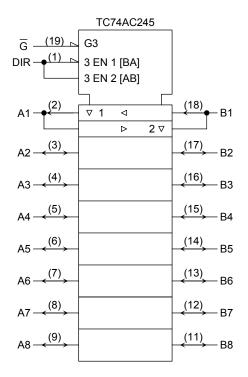


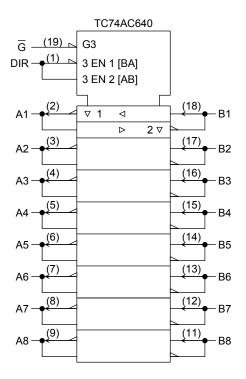
#### **Pin Assignment**





#### **IEC Logic Symbol**







#### **Truth Table**

Inputs		Fund	ction	Outputs			
G	DIR	A Bus	B Bus	AC245	AC640		
L	L	Output	Input	A = B	$A = \overline{B}$		
L	Н	Input	Output	B = A	$B = \overline{A}$		
Н	Х	2	7	Z	Z		

X: Don't care

Z: High impedance

#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40°C to 65°C. From Ta = 65°C to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

# **Operating Range (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	$V_{CC}$	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	٧	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	−40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V	
input noe and ian time	αναν	0 to 20 (V <sub>CC</sub> = 5 ± 0.5 V)	115/ V	

Note: The operating range is required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.



#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
Characteristics	Cymbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic	
	V <sub>IH</sub>			2.0	1.50	_	_	1.50	_		
High-level input voltage			_		3.0	2.10	_	_	2.10	_	V
0				5.5	3.85	_	1	3.85	_		
		_		2.0	_	_	0.50	_	0.50	V	
Low-level input voltage	$V_{IL}$			3.0	_	_	0.90	_	0.90		
0					5.5	-	_	1.65	_	1.65	
					2.0	1.9	2.0	_	1.9	_	- V
	V <sub>ОН</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA		3.0	2.9	3.0	_	2.9	_	
High-level output					4.5	4.4	4.5	_	4.4	_	
voltage			I <sub>OH</sub> = -4 mA		3.0	2.58	_	_	2.48	_	
			I <sub>OH</sub> = −24 mA		4.5	3.94	_	_	3.80	_	
			I <sub>OH</sub> = −75 mA	(Note)	5.5	_	_	_	3.85	_	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>			2.0	_	0.0	0.1	_	0.1	
			I <sub>OL</sub> = 50 μA		3.0	_	0.0	0.1	_	0.1	
Low-level output					4.5	_	0.0	0.1	_	0.1	V
voltage			I <sub>OL</sub> = 12 mA		3.0	_	_	0.36	_	0.44	V
			I <sub>OL</sub> = 24 mA		4.5	_	_	0.36	_	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	_	_	_	_	1.65	
3-state output off-state current	loz	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5		_	±0.5	_	±5.0	μΑ	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μΑ	
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	8.0	_	80.0	μΑ	

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Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.



#### AC Characteristics ( $C_L$ = 50 pF, $R_L$ = 500 $\Omega$ , input: $t_r$ = $t_f$ = 3 ns)

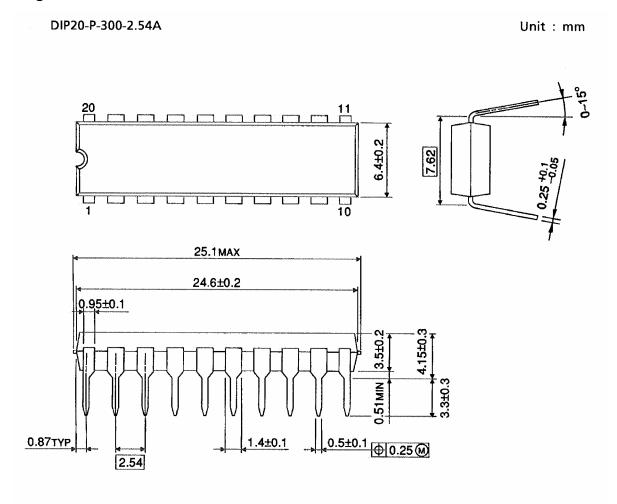
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t <sub>pLH</sub>		$3.3 \pm 0.3$	_	7.0	10.9	1.0	12.4	ns
time (Note 2)	$t_{pHL}$	_	5.0 ± 0.5	_	5.0	7.5	1.0	8.5	
Propagation delay	t <sub>pLH</sub>	-	3.3 ± 0.3	_	6.4	10.0	1.0	11.4	ns
time (Note 3)	$t_{pHL}$		5.0 ± 0.5	_	4.8	7.0	1.0	8.0	
Output anable time	t <sub>pZL</sub>	-	3.3 ± 0.3	_	9.3	15.3	1.0	17.4	ns
Output enable time	$t_{pZH}$		5.0 ± 0.5	_	7.1	10.5	1.0	12.0	
Output disable time	t <sub>pLZ</sub>	_	$3.3 \pm 0.3$	_	7.1	11.4	1.0	13.0	20
Output disable time	$t_{pHZ}$		5.0 ± 0.5	_	5.9	8.7	1.0	10.0	ns
Input capacitance	C <sub>IN</sub>	DIR, G		_	5	10	_	10	pF
Bus input capacitance	C <sub>I/O</sub>	A <sub>n</sub> , Bn		_	13	_	_	_	pF
Power dissipation	C <sub>PD</sub>	TC74AC245		_	38	_	_	_	
capacitance	(Note 1)	TC74AC640		_	36	_	_	_	pF

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} \cdot I_{CC} / 8$  (per bit)

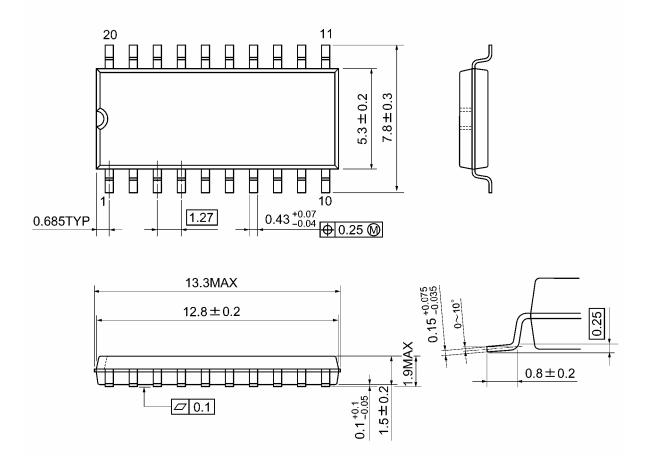
Note 2: For TC74AC245 only Note 3: For TC74AC640 only



Weight: 1.30 g (typ.)



SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

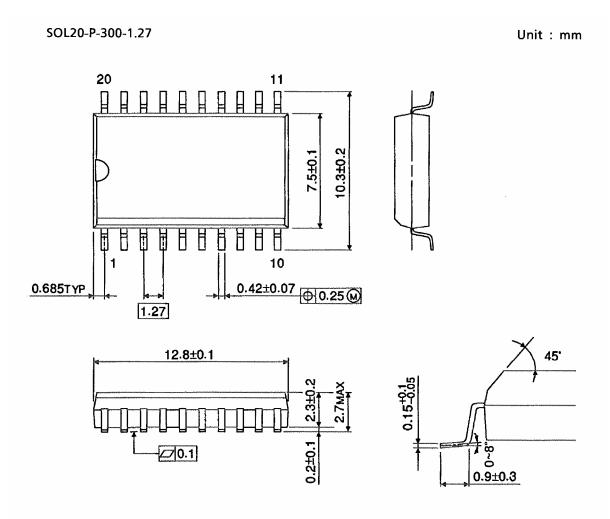


SOP20-P-300-1.27 Unit: mm 20 11  $5.3 \pm 0.2$ 7.8±0.3 (300mil) 7.62 B 10 0.43±0.1 (0.25 M) 0.685TYP 1.27 13.3MAX 12.8±0.2 **2**0.1 0.8±0.2

Weight: 0.22 g (typ.)



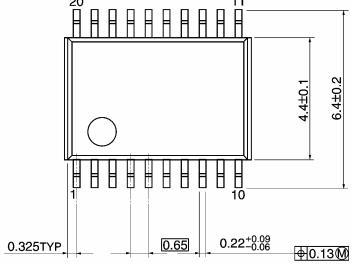
# **Package Dimensions (Note)**

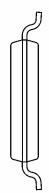


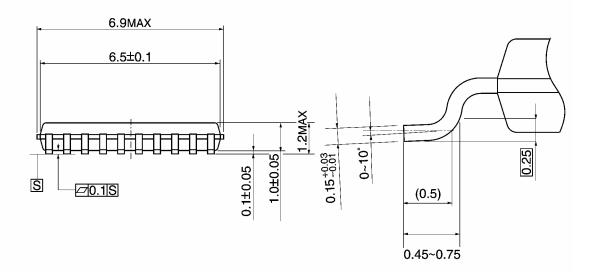
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

TSSOP20-P-0044-0.65A Unit: mm







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Weight: 0.08 g (typ.)

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20070701-EN

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